

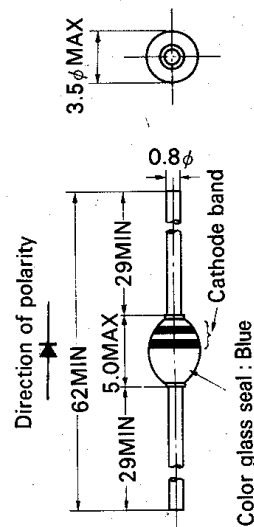
FEATURES

- V11 is a device developed for switching applications, with a reverse recovery time of $0.4\mu\text{sec}$. This product is optimum for use in high-frequency circuits such as television horizontal deflection circuits.
- Due to employment of the glass encapsulation that gained high repute in V03/V06, great convenience is provided for build-in wiring.
- Because of strict quality control and steady mass production, this diode offers uniform characteristics and remarkably high reliability.

特 長

- この製品は逆回復時間を $0.4\mu\text{sec}$ に押えスイッチング用として開発した素子で、テレビの水平偏回路等、高周波回路に最適です。
- 構造は V03/V06 で好評を博しましたガラスポデーですから組込み配線に大変便利であります。
- 厳密な品質管理と安定した量産を行なっておりますので、特性は均一であり、極めて信頼度の高いダイオードです。

OUTLINE DRAWING



Type	Direction of polarity
V11J(800V)	Green
V11L(1,000V)	Yellow
V11M(1,300V)	Black
V11N(1,500V)	Red

MAXIMUM ALLOWABLE RATINGS

Hitachi Type			V11J	V11L	V11M	V11N
Items	Symbols	Units	1S 2323	1S 2324	1S 2325	1S 2326
Repetitive Peak Reverse Voltage	V_{RRM}	V	800	1,000	1,300	1,500
Non-repetitive Peak Reverse Voltage	V_{RSM}	V	1,000	1,300	1,600	1,800
Average Forward Current	I_o	A	0.4 (Single-phase, half-wave 180° conduction ambient temperature 20°C)			
Peak One-cycle Surge Current	I_{TSM}	A	25 (10msec conduction, sine half-wave 1 cycle)			
I^2t Limit Value	I^2t	$A^2\text{sec}$	3.0 (Time=2~10msec. I=RMS value)			
Operating Temperature	T_j	°C	-40~+125			
Storage Temperature	T_{stg}	°C	-40~+150			
Weight		g	0.35			

CHARACTERISTICS

Items	Symbols	Units	Ratings
Maximum Reverse Current	I_{RM}		—
Maximum Forward Voltage Drop	V_{FM}	V	3.0 (Single-phase, half-wave peak value 1.6A, conduction angle 180°, T_j : 25°C)
Reverse Recovery Time	t_{rr}	μsec	0.4 (T_j : 25°C, Measuring conditions are based on test circuit)
Thermal Resistance	R_{th}	°C/W	— (Junction to Air)